General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

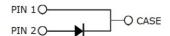
Applications

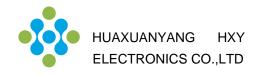
- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Qty(PCS)	
HIDK10G65C5XTMA2	TO-263	800	









Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	VRRM	650	V	
Surge Peak Reverse Voltage	Vrsm	650	V	
DC Peak Reverse Voltage	VR	650	V	
Continuous Forward Current Tc = 25°C Tc = 135°C Tc = 160°C	lF	30 15 10	А	
Repetitive Peak Forward Surge Current Tc = 25°C,tp=10ms,Half Sine Pulse Tc = 110°C,tp=10ms,Half Sine Pulse	İFRM	45 27	А	
Non-Repetitive Forward Surge Current $T_C = 25^{\circ}C, t_p=10 \text{ms}, Half Sine Pulse }$ $T_C = 110^{\circ}C, t_p=10 \text{ms}, Half Sine Pulse }$	IFSM	80 70	А	
i^2 dt value $T_C = 25^{\circ}C, t_p = 10 ms, Half Sine Pulse T_C = 110^{\circ}C, t_p = 10 ms, Half Sine Pulse$	∫ i²dt	31.7 24.3	A²s	
Power dissipation $Tc = 25^{\circ}C$ $Tc = 110^{\circ}C$	Ptot	92 40	W	
Operating junction Range	Tj	-55 to +175	°C	
Storage temperature Range	T _{stg}	-55 to +150	°C	

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal resistance, junction - case.	RthJC	1.62	°C/W



Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value		Unit	Test Condition		
i arameter	Symbol	min.	typ.	max.	Oille	rest condition	
Forward Voltage	VF				٧	I _F =10A	
		-	1.3	1.5		T _j =25°C	
		-	1.6	-		Tj=175°C	
Reverse Current	lĸ				μΑ	Vr=650V	
		-	-	50		T _j =25°C	
		-	-	200		T _j =175°C	
Total Capacitive Charge	Qc	-	27	-	nC	V _R =400V,T _j =25℃	
						$Q_C = \int_0^{V_R} C(V) dV$	
Total Capacitance	С				pF	Tj=25℃, f=1MHz	
		-	561	-		V _R =0V	
		-	55	-		V _R =200V	
		-	43	-		Vr=400V	

Characteristics Curve:

Fig 1: Forward Characteristics

20

Tj=25°C

Tj=75°C

Tj=175°C

Tj=175°C

V_F (V)

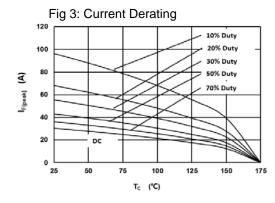
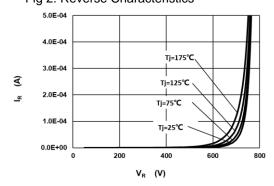


Fig 2: Reverse Characteristics



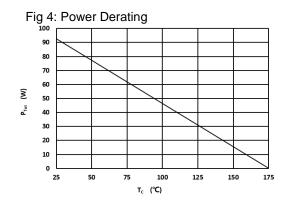


Fig 5: Capacitance vs. Reverse Voltage

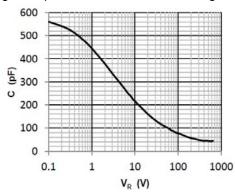


Fig 6: Reverse Charge vs. Reverse Voltage

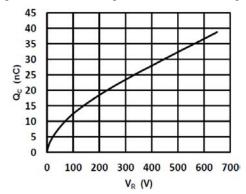


Fig 7: Typical Capacitance Stored Energy

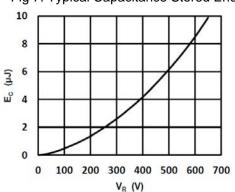
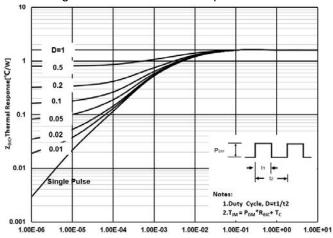


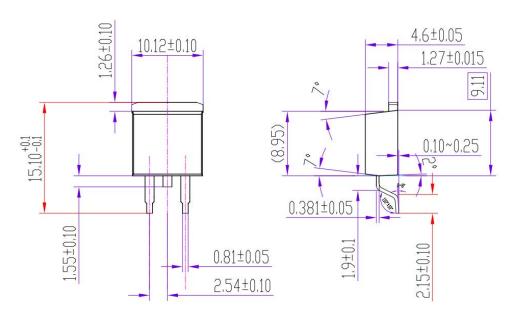
Fig 8: Transient Thermal Impandance

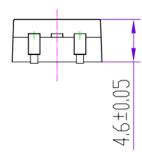


T , Rectangular Pulse Duration [sec]

Package Dimensions

Package TO-263





HIDK10G65C5XTMA2

Silicon Carbide Schottky Diode

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